

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Johannes Baur et al.  
Patent No. : 7,169,632  
Issue Date : January 30, 2007  
Serial No. : 10/657,841  
Filed : September 9, 2003

Art Unit : 2812  
Examiner : Savitri Mulpuri  
Conf. No. : 2117

Title : RADIATION-EMITTING SEMICONDUCTOR COMPONENT AND METHOD  
FOR PRODUCING THE SEMICONDUCTOR COMPONENT

**MAILSTOP CERTIFICATE OF CORRECTIONS**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

TRANSMITTAL OF REQUEST FOR CERTIFICATE OF CORRECTION

Applicant hereby requests that a certificate of correction be issued for the above-referenced patent in accordance with the attached request.

All errors sought to be corrected were made in printing by the U.S. Patent and Trademark Office, as evidenced by the attached initialed PTO Forms 1449, and no fee is believed to be due.

Please apply any other required fees to deposit account 06-1050, referencing the attorney docket number shown above.

Respectfully submitted,

Date: May 9, 2007

  
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# UNITED STATES PATENT AND TRADEMARK OFFICE

## CERTIFICATE OF CORRECTION

Page 1 of 2

PATENT NO. : 7,169,632  
 APPLICATION NO : 10/657,841  
 DATED : JANUARY 30, 2007  
 INVENTOR(S) : JOHANNES BAUR, DOMINIK EISERT, MICHAEL FEHRER, BERTHOLD HAHN, VOLKER  
 HÄRLE, MARIANNE ORTMANN, UWE STRAUSS, JOHANNES VÖKL AND ULRICH  
 ZEHNDER

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Page 2, column 1, line 8,  
**U.S. PATENT DOCUMENTS,**

insert --	6,291,839 B1	09/2001	Lester
	3,343,026	09/1967	Luechinger et al.
	5,814,839	09/1998	Hosoba
	5,087,674	02/1992	Gardner et al.
	2003/0116791 A1	06/2003	Baptist et al.
	2003/0127654 A1	07/2003	Eisert et al.
	6,229,160 B1	05/2001	Krames et al. --

Page 2, column 2, line 7,  
**FOREIGN PATENT DOCUMENTS,**

insert --	DE	199 27 945 A1	03/2000
	DE	198 07 758 A1	12/1998
	DE	43 24 325 A1	01/1994
	DE	42 18 806 A1	12/1993
	DE	27 27 508 A1	01/1979

### MAILING ADDRESS OF SENDER:

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CERTIFICATE OF CORRECTION**

Page 2 of 2

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ZEHNDER

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

WO	01/93310 A2	12/2001
WO	01/61765 A1	08/2001
UK	2 271 087 A	04/1994
EP	0 611 131 A1	08/1994
EP	0 405 757 A2	01/1991
EP	0 442 002 A1	08/1991
EP	0 810 674 A2	12/1997
JP	03227078 A	10/1991
JP	61 110 476	05/1986 --

Page 2, column 2, line 7,

**OTHER PUBLICATIONS**

insert -- J. Zhang et al. "Precise microfabrication of wide band gap semiconductors (SiC and GaN) by VUV-UV multiwavelength laser ablation", Applied Surface Science, Vol. 127-129, pp. 793-799, 1998.

W. N. Carr. "Photometric Figures of Merit for Semiconductor Luminescent Sources Operating in Spontaneous Mode", Infrared Physics, Vol. 6, pp. 1-19, 1966. --

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Minneapolis, Minnesota 55440-1022

## FORM PTO-1449 (SUBSTITUTE)

U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICEINFORMATION DISCLOSURE  
STATEMENT BY APPLICANT  
(37 CFR 1.98(b))Attorney Docket No.: P2001,0176  
Appl. No.:

Applicant: JOHANNES BAUR ET AL.

Filing Date: September 9, 2003  
Group Art Unit:

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
<i>SM</i>	A	6,291,839 B1	9/18/01	Lester			
	B	3,343,026	9/19/67	Luechinger et al.			
	C	5,814,839	9/29/98	Hosoba			
	D	5,087,674	2/11/92	Gardner et al.			
	E	2003/0116791 A1	6/26/03	Baptist et al.			
	F	2003/0127654 A1	7/10/03	Eisert et al.			
<i>SM</i>	G	6,229,160 B1	5/8/01	Krames et al.			
	H						
	I						

## FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES   NO
<i>SM</i>	J	199 27 945 A1	3/23/00	Germany			
	K	198 07 758 A1	12/10/98	Germany			
	L	43 24 325 A1	1/27/94	Germany			
	M	42 18 806 A1	12/9/93	Germany			
<i>SM</i>	N	27 27 508 A1	1/4/79	Germany			

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

EXAMINER	<i>SM</i>	DATE CONSIDERED <i>3/12/05</i>

<b>FORM PTO-1449 (SUBSTITUTE)</b>  U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE  <b>INFORMATION DISCLOSURE          STATEMENT BY APPLICANT          (37 CFR 1.98(b))</b>				Attorney Docket No.: P2001,0176 Appl. No.:  Applicant: JOHANNES BAUR ET AL.  Filing Date: September 9, 2003 Group Art Unit:			
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EXAMINER INITIALS	A	PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
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FOREIGN PATENT DOCUMENT							
		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES / NO
<i>GM</i>  <i>GM</i>	J	01/93310 A2	12/6/01	WIPO			
	K	01/61765 A1	8/23/01	WIPO			
	L	2 271 087 A	4/6/94	U.K.			
	M	0 611 131 A1	8/17/94	Europe			
	N	0 405 757 A2	1/2/91	Europe			

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)		
EXAMINER <i>G. ...</i>	DATE CONSIDERED <i>3/1/04</i>	

<b>FORM PTO-1449 (SUBSTITUTE)</b>  U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE  <b>INFORMATION DISCLOSURE          STATEMENT BY APPLICANT</b> (37 CFR 1.98(b))				Attorney Docket No.: P2001,0178 Appl. No.:  Applicant: JOHANNES BAUR ET AL.  Filing Date: September 9, 2003 Group Art Unit:			
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EXAMINER INITIALS	A	PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
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FOREIGN PATENT DOCUMENT							
		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES / NO
52	J	0 442 002 A1	8/21/91	Europe			
	K	0 810 674 A2	12/3/97	Europe			
52	L	03227078 A	10/8/91	Japan			
	M						
	N						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)	
EXAMINER <i>S. ...</i>	DATE CONSIDERED <i>3/17/03</i>

FORM PTO-1449 (SUBSTITUTE)

U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICE

Attorney Docket No.:

P2001,0176

Applic. No.

10/657,841

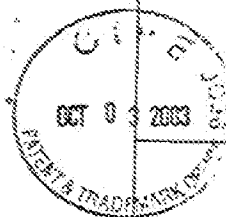
Applicant

Johannes Baur et al.

Filing Date

September 9, 2003

Group Art Unit

INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT  
(37 CFR 1.98(b))

## U.S. PATENT DOCUMENTS

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## FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES   NO
	J	61 110 476	05/26/86	Japan			X
	K						
	L						
	M						
	N						

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

	D	J. Zhang et al.: "Precise microfabrication of wide band gap semiconductors (SiC and GaN) by VUV-UV multiwavelength laser ablation", <i>Applied Surface Science</i> , Vol. 127-129, 1998, pp. 793-799
	P	W. N. Carr: "Photometric Figures Of Merit For Semiconductor Luminescent Sources Operating in Spontaneous Mode", <i>Infrared Physics</i> , 1966, Vol. 6, pp. 1-19

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.